NSN 5961-01-211-0155

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-211-0155 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.205 inches and 0.225 inches Overall Diameter: Between 0.119 inches and 0.127 inches **End Application:** An/vrc-83 **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** T.O. 31r2-2vrc83-3; junction pattern arrangement: pin **Test Data Document:** 37695-619906 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: No